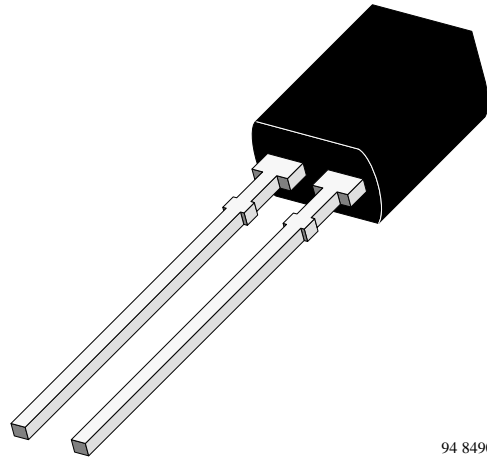


Silicon PIN Photodiode

Description

BPW83 is a high speed and high sensitive PIN photodiode in a flat side view plastic package. The epoxy package itself is an IR filter, spectrally matched to GaAs or GaAlAs IR emitters ($\lambda_p \geq 800\text{nm}$).

The large active area combined with a flat case gives a high sensitivity at a wide viewing angle.



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Features

- Large radiant sensitive area ($A=7.5 \text{ mm}^2$)
- Wide angle of half sensitivity $\varphi = \pm 65^\circ$
- High radiant sensitivity
- Fast response times
- Small junction capacitance
- Plastic case with IR filter
- Suitable for near infrared radiation
- Especially for GaAlAs emitters with $\lambda_p=870\text{nm}$

Applications

High speed photo detector

Absolute Maximum Ratings

 $T_{amb} = 25^{\circ}\text{C}$

| Parameter | Test Conditions | Symbol | Value | Unit |
|-------------------------------------|-----------------------------------|------------|------------|--------------------|
| Reverse Voltage | | V_R | 60 | V |
| Power Dissipation | $T_{amb} \leq 25^{\circ}\text{C}$ | P_V | 215 | mW |
| Junction Temperature | | T_j | 100 | $^{\circ}\text{C}$ |
| Storage Temperature Range | | T_{stg} | -55...+100 | $^{\circ}\text{C}$ |
| Soldering Temperature | $t \leq 5\text{ s}$ | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal Resistance Junction/Ambient | | R_{thJA} | 350 | K/W |

Basic Characteristics

 $T_{amb} = 25^{\circ}\text{C}$

| Parameter | Test Conditions | Symbol | Min | Typ | Max | Unit |
|--------------------------------|---|-----------------|-----|---------------------|-----|-----------------------------|
| Breakdown Voltage | $I_R = 100\ \mu\text{A}, E = 0$ | $V_{(BR)}$ | 60 | | | V |
| Reverse Dark Current | $V_R = 10\ \text{V}, E = 0$ | I_{ro} | | 2 | 30 | nA |
| Diode Capacitance | $V_R = 0\ \text{V}, f = 1\ \text{MHz}, E = 0$ | C_D | | 70 | | pF |
| Diode Capacitance | $V_R = 3\ \text{V}, f = 1\ \text{MHz}, E = 0$ | C_D | | 25 | 40 | pF |
| Open Circuit Voltage | $E_e = 1\ \text{mW}/\text{cm}^2, \lambda = 870\ \text{nm}$ | V_o | | 350 | | mV |
| Short Circuit Current | $E_e = 1\ \text{mW}/\text{cm}^2, \lambda = 870\ \text{nm}$ | I_k | | 38 | | μA |
| Reverse Light Current | $E_e = 1\ \text{mW}/\text{cm}^2, \lambda = 870\ \text{nm}, V_R = 5\ \text{V}$ | I_{ra} | 43 | 45 | | μA |
| Angle of Half Sensitivity | | φ | | ± 65 | | deg |
| Wavelength of Peak Sensitivity | | λ_p | | 950 | | nm |
| Range of Spectral Bandwidth | | $\lambda_{0.5}$ | | 790...1050 | | nm |
| Noise Equivalent Power | $V_R = 10\ \text{V}, \lambda = 870\ \text{nm}$ | NEP | | 4×10^{-14} | | $\text{W}/\sqrt{\text{Hz}}$ |
| Rise Time | $V_R = 10\ \text{V}, R_L = 1\ \text{k}\Omega, \lambda = 820\ \text{nm}$ | t_r | | 100 | | ns |
| Fall Time | $V_R = 10\ \text{V}, R_L = 1\ \text{k}\Omega, \lambda = 820\ \text{nm}$ | t_f | | 100 | | ns |

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

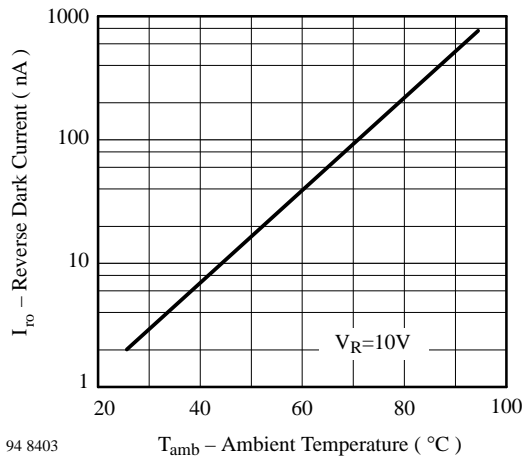


Figure 1 : Reverse Dark Current vs. Ambient Temperature

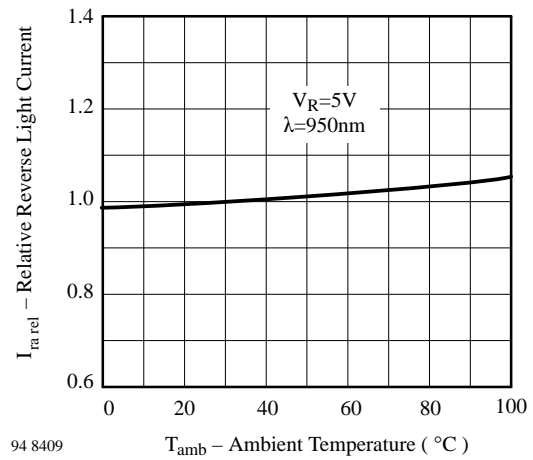


Figure 2 : Relative Reverse Light Current vs. Ambient Temperature

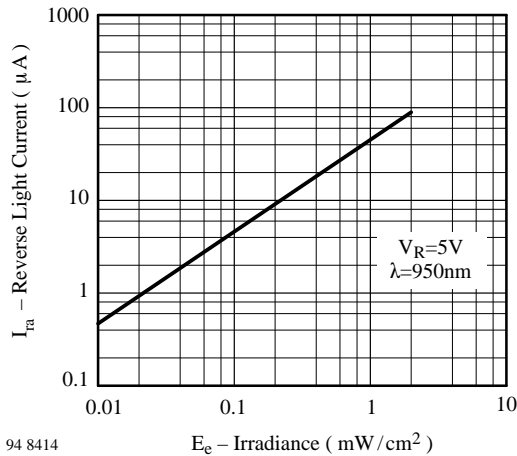


Figure 3 : Reverse Light Current vs. Irradiance

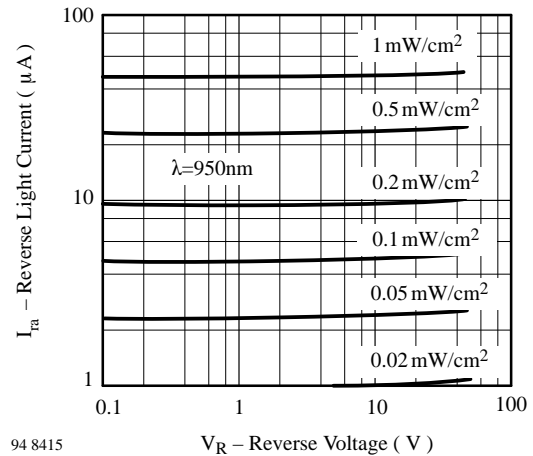


Figure 4 : Reverse Light Current vs. Reverse Voltage

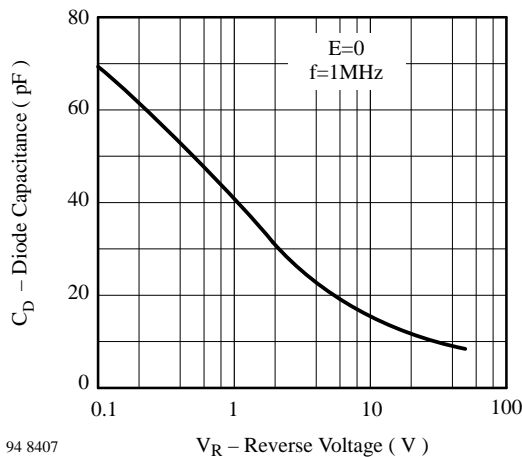


Figure 5 : Diode Capacitance vs. Reverse Voltage

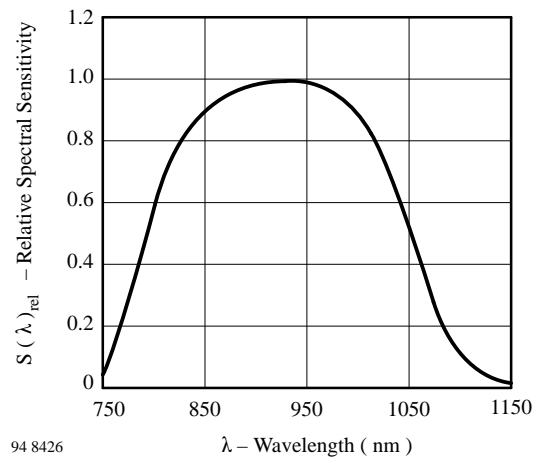
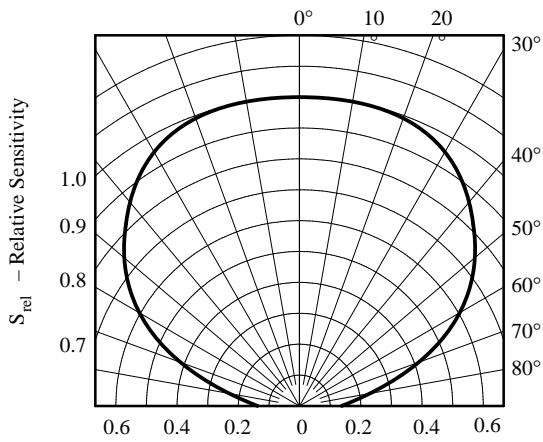


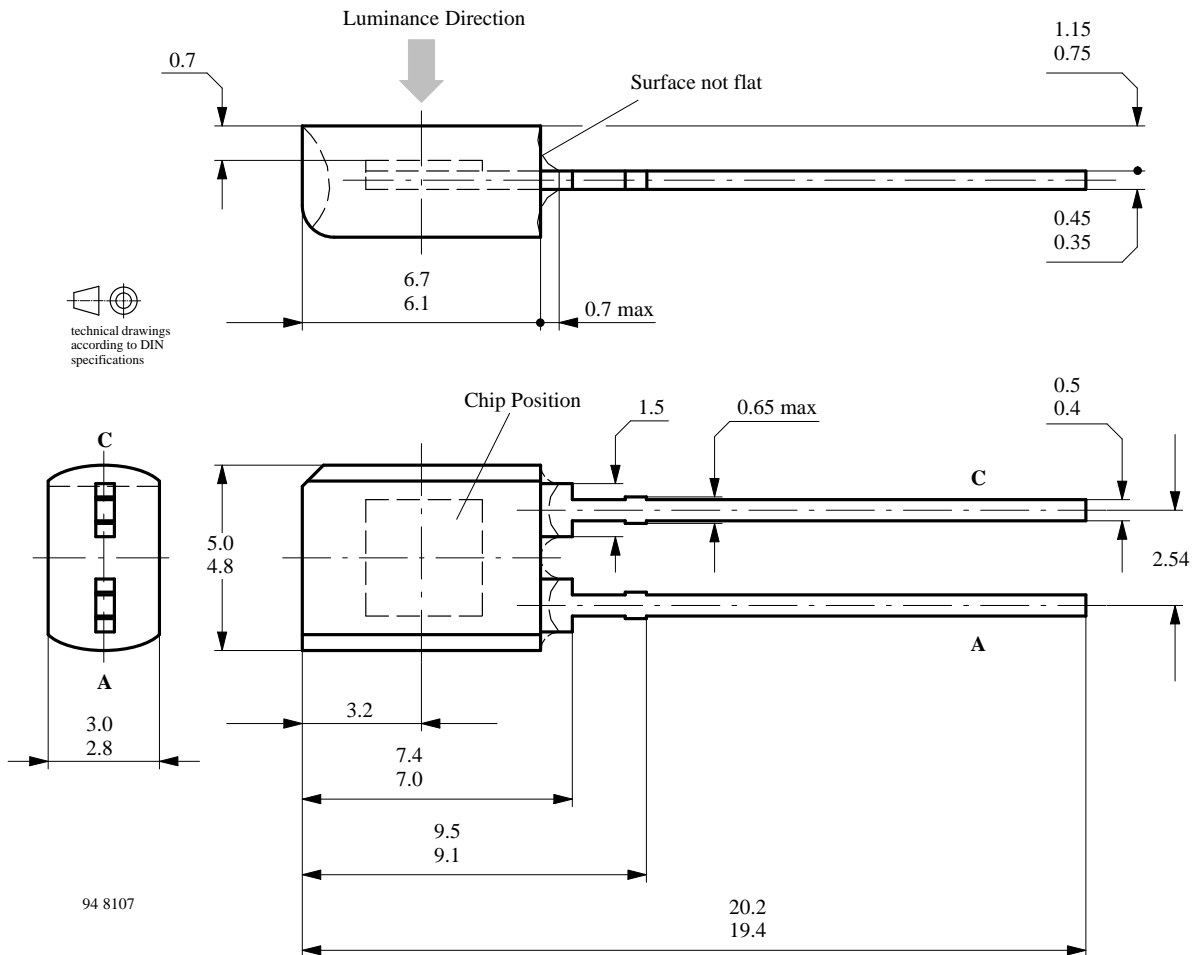
Figure 6 : Relative Spectral Sensitivity vs. Wavelength



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Figure 7 : Relative Radiant Sensitivity vs. Angular Displacement

Dimensions in mm



We reserve the right to make changes to improve technical design without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax Number: 49 (0)7131 67 2423